

800mA Dual-rail Very Low Dropout LDO

General Description

The ET551XX series are CMOS-based low-dropout, low-power linear regulators, offering 800mA with NMOS pass transistor and a separate bias supply voltage (VBIAS) . The device provides very stable, accurate output voltage with low noise, high ripple rejection and low supply current suitable for space constrained, noise sensitive application. The ET551XX series consist of an accurate voltage-reference block, an error amplifier, a thermal-shutdown circuit, and a current limit circuit.

The ET551XX series are available in the DFN4(1.2mm×1.2mm) or DFN6(1.2mm×1.2mm) package.

Features

- Wide VIN Input Voltage Range: 0.8V to 5.5V
- Wide VBIAS Voltage Range: 2.4V to 5.5V
- Output Voltage Range: 0.8V to 2.1V (Fixed Version:1.05V,1.1V,1.2V and etc)
0.8V to 3.6V (ADJ version: Externally set)
- Very Low VBIAS Input Current of Typ. 80μA
- Ultra Low Dropout: Typ. 200mV at 800mA, 1.1V Output, 3.3V Bias
- Built-in Over Current Protection and Thermal Shutdown Circuit
- Built-in Auto-discharging Circuit
- Built-in Under Voltage Lock-out
- Stable with a 2.2μF Ceramic Capacitor
- Package: DFN4(1.2mm × 1.2mm × 0.4mm) or DFN6(1.2mm × 1.2mm × 0.4mm)

Applications

- Constant-voltage power supply for battery-powered device
- Constant-voltage power supply for smartphones, tablets
- Constant-voltage power supply for cameras, DVRs, STB and camcorders

Device information

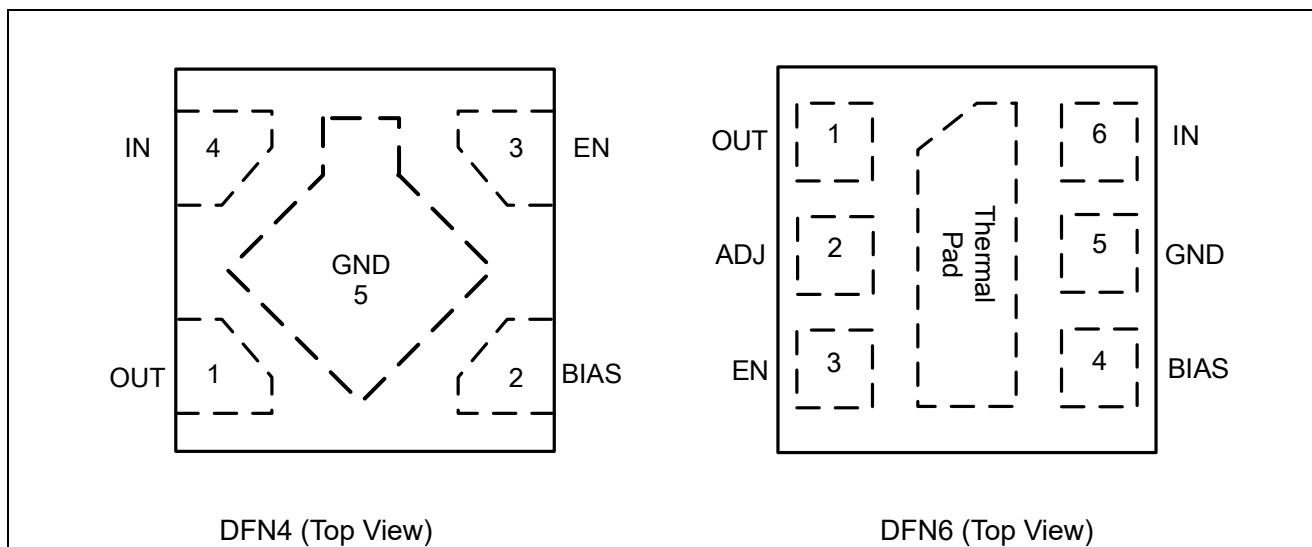
ET 551 XX X B

<u>XX</u> Output Voltage		<u>X</u> Package		<u>B</u> Auto-discharge Function	
XX	Fixed X.XV	Y	DFN4 -1.2×1.2	B	With
ADJ	ADJ Version	Y1	DFN6 -1.2×1.2		Auto-discharge Function

Part No.	Package	Packing Option	MSL
ET551XXYB	DFN4 -1.2×1.2	Tape and Reel, 3K/Reel	1
ET551ADJY1B	DFN6 -1.2×1.2	Tape and Reel, 3K/Reel	1

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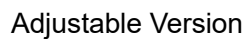
Pin Configuration



Pin Function

Pin Name		Symbol	Pin Description
DFN4	DFN6		
1	1	OUT	The power output of the device.
2	4	BIAS	Input voltage for controlling circuit.
3	3	EN	Enable Input.
4	6	IN	Input voltage Pin. Large bulk capacitance should be placed closely to this pin. A 1 μ F ceramic capacitor is recommended at this pin.
5	5	GND	Ground pin. Thermal PAD.
	2	ADJ	Adjustable Regulator Feedback Input. Connect to output voltage resistor divider central node.

Block Diagram



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Functional Description

The ET551XX dual-rail very low dropout voltage regulator is using NMOS pass transistor for output voltage regulation from V_{IN} voltage. All the low current internal control circuitry is powered from the V_{BIAS} voltage.

The use of an NMOS pass transistor offers several advantages in applications. Unlike PMOS topology devices, the output capacitor has reduced impact on loop stability. V_{IN} to V_{OUT} operating voltage difference can be very low compared with standard PMOS regulators in very low V_{IN} applications.

The ET551XX offers smooth monotonic start-up.

Input and output Capacitor

The device is designed to be stable for ceramic output capacitors with Effective capacitance in the range from 2.2 μ F to 4.7 μ F. The device is also stable with multiple capacitors in parallel, having the total effective capacitance in the specified range. In applications where no low input supplies impedance available (PCB inductance in V_{IN} and/or V_{BIAS} inputs as example), the recommended $C_{IN} = 1\mu$ F and $C_{BIAS} = 0.1\mu$ F or greater.

Enable Pin Operation

The ET551XX is turned on by setting the EN pin to "H". The threshold limits are covered in the electrical characteristics table in this datasheet. When the EN pin is not used, connect the EN pin with V_{BIAS} to keep the LDO in operating mode.

Current Limit Protection

When output current of V_{OUT} pin is higher than current limit threshold or the V_{OUT} pin is direct short to GND, the current limit protection will be triggered and clamp the output current at a predesigned level to prevent over-current and thermal damage.

Thermal Shutdown Protection

Thermal protection disables the output when the junction temperature rises to approximately +165°C, allowing the device to cool down. When the junction temperature reduces to approximately +145°C the output circuit is enabled again. Depending on power dissipation, thermal resistance, and ambient temperature, the thermal protection circuit may cycle on and off. This cycling limits the heat dissipation of the regulator, protecting it from damage due to overheating.

Auto Discharging

When the EN pin set to "L", the output circuit will be disable immediately, and the Auto-Discharging circuit will be turned on to discharge the electric charge on output capacitor, and decrease the voltage of V_{OUT} in very short time. The Auto-Discharging function is optional.

Output Voltage Adjust(Only for ADJ Version)

The required output voltage of Adjustable devices can be adjusted from V_{REF} to 3.6 V using two external resistors. Typical application schematics is shown blow.

$$V_{OUT} = V_{REF} \times (1 + R1/R2)$$

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Typical value of V_{REF} is 0.8V. It is recommended to keep the total serial resistance of resistors ($R1+R2$) not greater than 100K Ω .

The output voltage needs to take into account the error caused by the resistance accuracy.

Absolute Maximum Ratings

Item	Rating	Unit
Input Voltage(VIN Pin)	-0.3 to 6.0	V
Input Voltage (VBIAS Pin)	-0.3 to 6.0	V
Input Voltage (EN Pin)	-0.3 to 6.0	V
Input Voltage (ADJ Pin)	-0.3 to 6.0	V
Output Voltage	-0.3 to 6.0	V
Maximum Load Current	800	mA
Maximum Power Consumption	640	mW
Storage Temperature Range	-65 to +150	°C
Operating Junction Temperature	-40 to +150	°C
ESD HBM	± 4000	V
ESD CDM	± 1500	V

Recommended Operating Conditions

Symbol	Item	Rating	Unit
V_{IN}	IN Input Voltage	$V_{OUT} + V_{DROP}$ to 5.5	V
V_{BIAS}	BIAS Input Voltage	2.7 to 5.5 & $V_{BIAS} \geq V_{OUT} + 1.4V$	V
I_{OUT}	Output Current	0 to 800	mA
T_A	Operating Ambient Temperature	-40 to 85	°C
C_{IN}	Effective Input Ceramic Capacitor Value	0.47 to 10	μF
C_{BIAS}	Effective Input Ceramic Capacitor Value	0.047 to 4.7	μF
C_{OUT}	Effective Output Ceramic Capacitor Value	2.2 to 4.7	μF
ESR	Input and Output Capacitor Equivalent Series Resistance	5 to 100	m Ω

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Electrical Characteristics

(Unless otherwise noted , $V_{IN}=V_{OUT}+0.3V$, $V_{BIAS}=V_{OUT}+1.6V$, $I_{OUT}=1mA$, $C_{IN}=1\mu F$, $C_{OUT}=2.2\mu F$, $C_{BIAS}=0.1\mu F$, $T_A=-40^{\circ}C\sim 85^{\circ}C$. Typical values are at. $T_A=25^{\circ}C$)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Input Voltage Range	$V_{IN}^{(1)}$	$V_{IN}>V_{OUT}$	$V_{OUT}+$ V_{DROP}		5.5	V
V_{BIAS} Voltage Range	V_{BIAS}	$V_{BIAS}\geq V_{OUT}+1.6V$	2.4		5.5	V
Under-voltage lock-out	V_{UVLO}	V_{BIAS} Rising/Hysteresis		1.6/0.2		V
V_{BIAS} Current	$I_{Q_ON}^{(4)}$	Active mode: $V_{EN}=H$		80	110	μA
	I_{Q_OFF}	$V_{EN}=L$		0.5	1.0	μA
Output Voltage	V_{OUT}	$I_{OUT}=1mA\sim 800mA$, $T_A=25^{\circ}C$	-2		2	%
Dropout Voltage	$V_{DROP}^{(2)}$	$I_{OUT}=500mA$, $V_{OUT}=1.1V$		125	187	mV
		$I_{OUT}=800mA$, $V_{OUT}=1.1V$		200	300	
Current Limit	I_{LIM}	$V_{OUT}=90\%V_{OUT}$	800	1150	1550	mA
Load Regulation	Reg_{LOAD}	$1mA\leq I_{OUT}\leq 800mA$		2	20	mV
V_{IN} Line Regulation	Reg_{LINE}	$V_{OUT}+0.3V\leq V_{IN}\leq 5V$ ($I_{OUT}=1mA$)		0.01	0.1	%/V
V_{BIAS} Line Regulation		$(V_{OUT}+1.6V)<V_{BIAS}<5.5V$, ($V_{IN}=V_{OUT}+0.3V$, $I_{OUT}=1mA$)		0.01	0.1	%/V
Ripple Rejection	$PSRR^{(3)}$	V_{IN} to V_{OUT} , $f=1kHz$, Ripple 0.2Vp-p, $I_{OUT}=30mA$		80		dB
		V_{BIAS} to V_{OUT} , $f=1kHz$, Ripple 0.2Vp-p, $I_{OUT}=30mA$		80		
Output Noise	$e_N^{(3)}$	$V_{IN}=1.6V$, $V_{OUT}=1.1V$, $f=10Hz$ to $100kHz$		$50\times$ V_{OUT}		μV_{RMS}
EN Pull-down Current	I_{EN}	$V_{EN}=5.5V$		0.5	1	μA
EN Input Voltage High	V_{ENH}		0.9			V
EN Input Voltage Low	V_{ENL}				0.4	V
Output resistance of auto discharge at off state	R_{DIS}	$V_{EN}=0V$, $V_{OUT}=0.5V$		150		Ω
Line transient	$V_{TRLN}^{(3)}$	$V_{IN}=V_{OUT}+0.3V$ to $5.5V$ in $10\mu s$, $I_{OUT}=1mA$, $T_A=25^{\circ}C$		18	30	mV
		$V_{IN}=5.5V$ to $V_{OUT}+0.3V$ in $10\mu s$, $I_{OUT}=1mA$, $T_A=25^{\circ}C$		18	30	mV
Load transient	$V_{TRLD}^{(3)}$	$I_{OUT}=1mA$ to $800mA$ in $10\mu s$ $V_{IN}=V_{OUT}+0.5V$, $T_A=25^{\circ}C$		120	180	mV
		$I_{OUT}=800mA$ to $1mA$ in $10\mu s$ $V_{IN}=V_{OUT}+0.5V$, $T_A=25^{\circ}C$		80	120	mV

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Electrical Characteristics(Continued)

(Unless otherwise noted , $V_{IN}=V_{OUT}+0.3V$, $V_{BIAS}=V_{OUT}+1.6V$, $I_{OUT}=1mA$, $C_{IN}=1\mu F$, $C_{OUT}=2.2\mu F$, $C_{BIAS}=0.1\mu F$, $T_A=-40^{\circ}C\sim 85^{\circ}C$. Typical values are at. $T_A=25^{\circ}C$)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Turn-On Time	t_{ON}	From assertion of V_{EN} to $V_{OUT}=98\%V_{OUT(NOM)}$		120		μs
Thermal Shutdown Temperature	$T_{SD}^{(3)}$	Temperature increasing		165		$^{\circ}C$
Thermal Shutdown Released Temperature	$T_{SR}^{(3)}$	Temperature decreasing		145		$^{\circ}C$

Notes:

1: The maximum input voltage should take into account the maximum power consumption ($P_{D(MAX)}$). The calculation formula is as follows:

$$P_{D(MAX)} = (V_{IN(MAX)} - V_{OUT}) \times I_{OUT}$$

The maximum power consumption of the circuit is 640mW.

$$V_{IN(MAX)} = 640mW / I_{OUT} + V_{OUT}$$

For example:

If $V_{OUT}=1.1V$, $I_{OUT}=800mA$, The maximum input voltage is $V_{IN(MAX)}=640mW / 800mA + 1.1=1.9V$

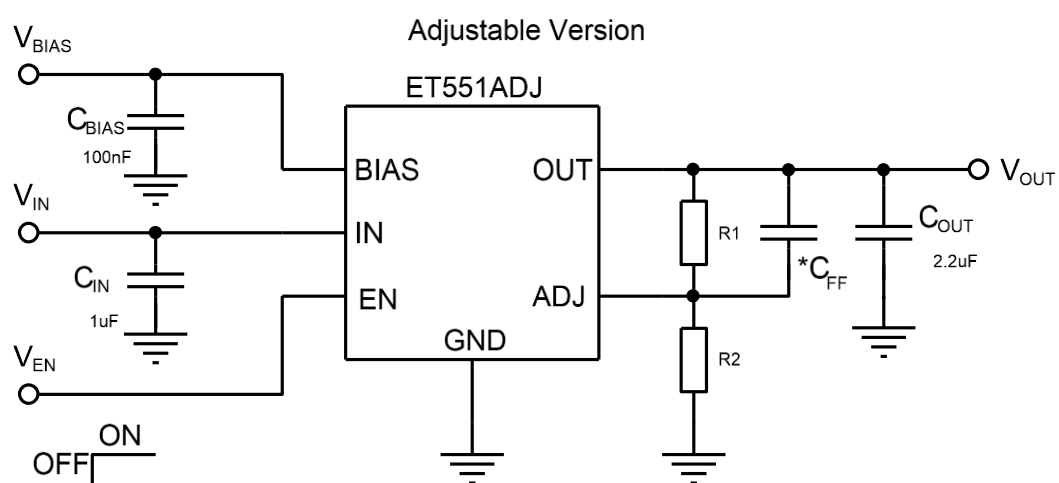
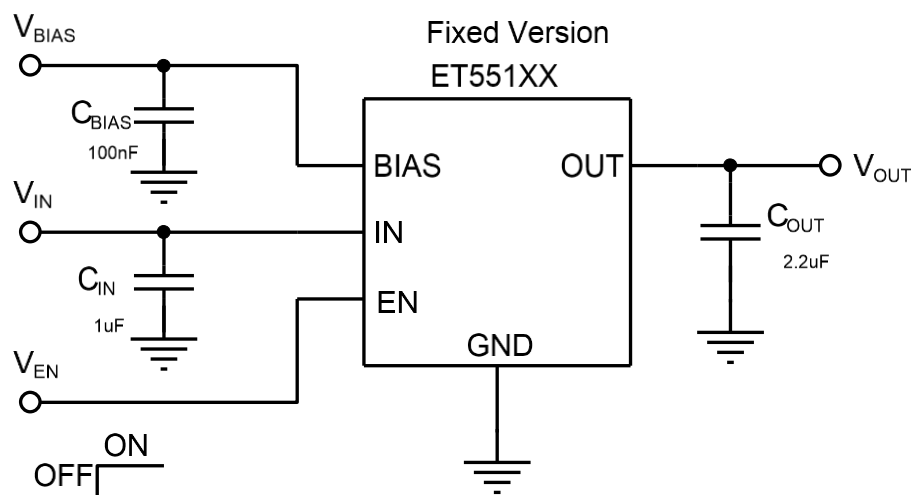
2: V_{DROP} FT test method: test the V_{OUT} voltage at $V_{SET} + V_{DROP MAX}$ with output current.

3: Guaranteed by design and characterization. not a FT item.

4: Since the power on process of BIAS needs a large current, the BIAS input voltage should have a current driving capacity of more than 120mA.

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Application Circuits



Note*: Adjust Version: $V_{OUT} = 0.8 \times (1 + R1/R2)$, $(R1 + R2)$ no greater than 100k Ω .

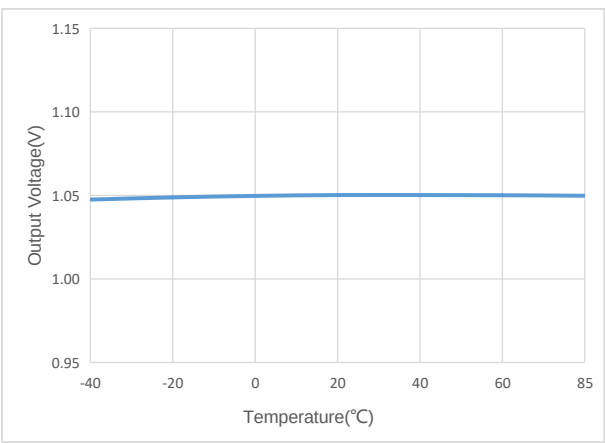
The feedforward capacitor CFF is optional for the optimization of transient response.

If BIAS input series resistor is used, it is recommended no greater than 20 Ω .

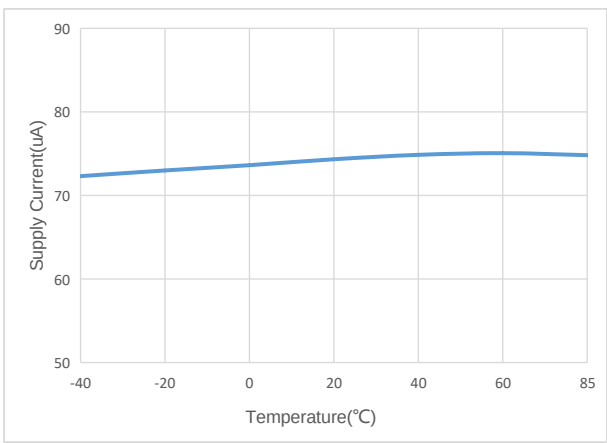
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Typical Characteristics

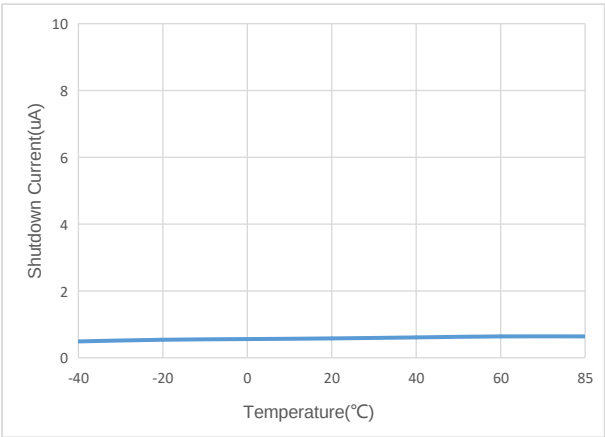
($V_{OUT}=1.05V$, $V_{IN}=V_{OUT}+0.3V$, $V_{BIAS}=V_{OUT}+1.6V$, $C_{IN}=1\mu F$, $C_{OUT}=2.2\mu F$, $C_{BIAS}=1\mu F$, $T_A=-40^{\circ}C\sim+85^{\circ}C$)



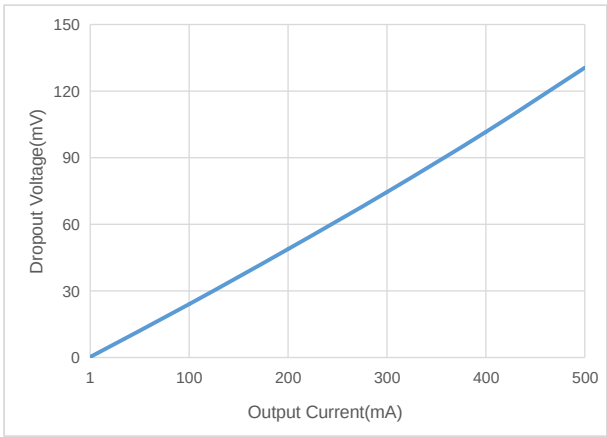
Output Voltage VS Temperature



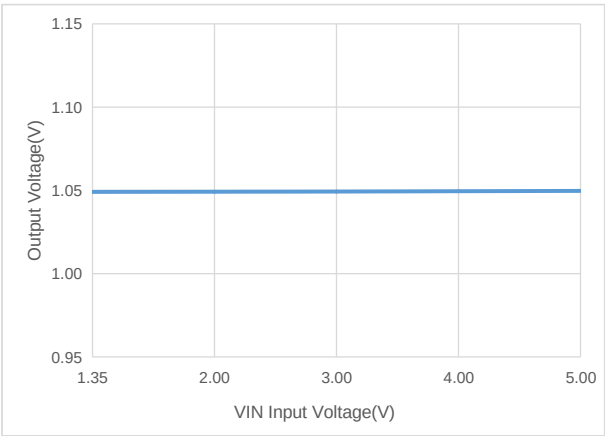
Supply Current VS Temperature



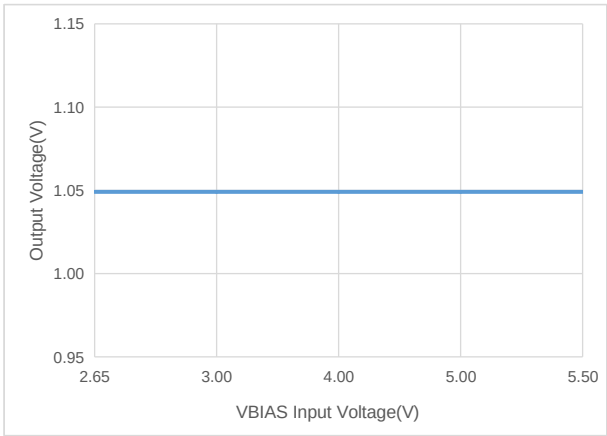
Shutdown Current VS Temperature



Dropout Voltage VS Output Current



Output Voltage VS VIN Input Voltage

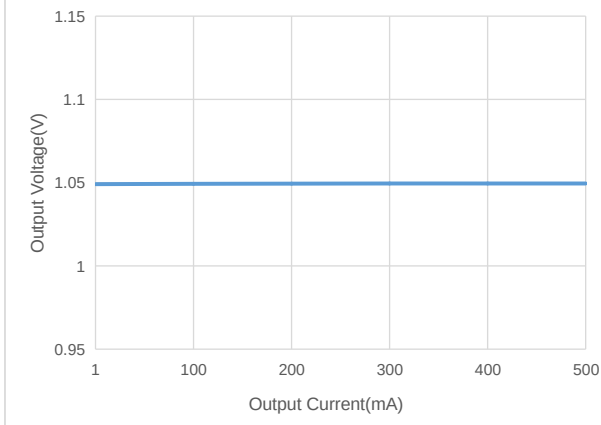


Output Voltage VS VBIAS Input Voltage

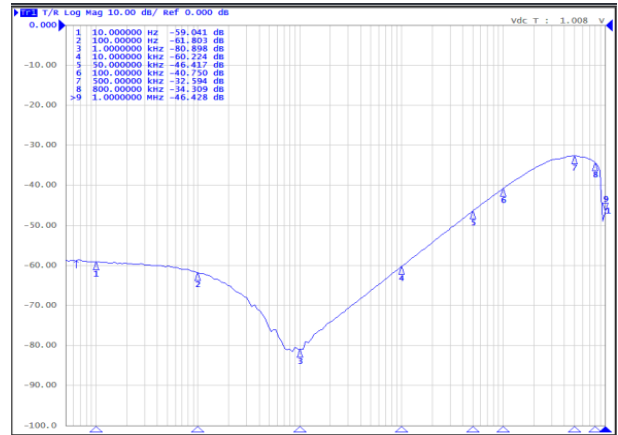
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Typical Characteristics(Continued)

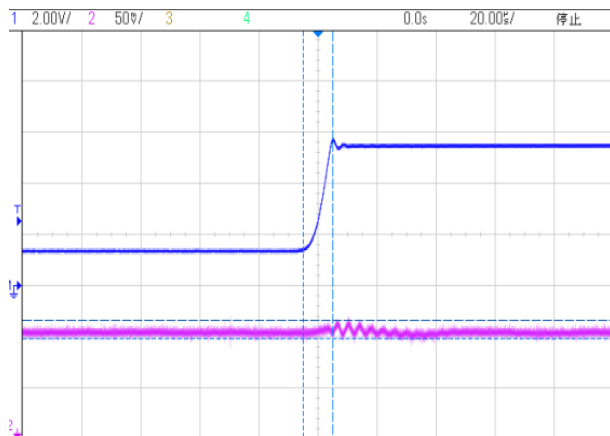
($V_{OUT}=1.05V$, $V_{IN}=V_{OUT}+0.3V$, $V_{BIAS}=V_{OUT}+1.6V$, $C_{IN}=1\mu F$, $C_{OUT}=2.2\mu F$, $C_{BIAS}=1\mu F$, $T_A=-40^{\circ}C\sim+85^{\circ}C$)



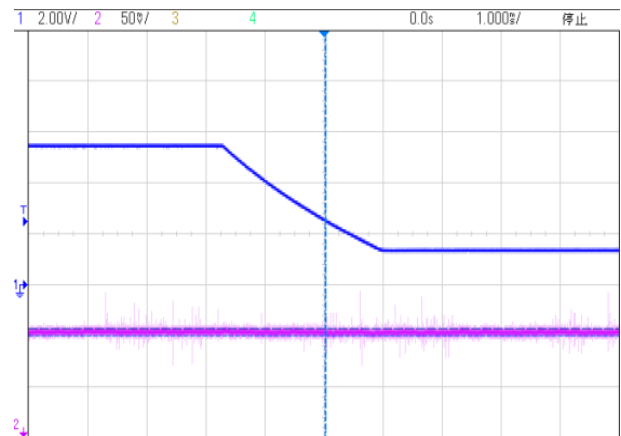
Output Voltage VS Output Current



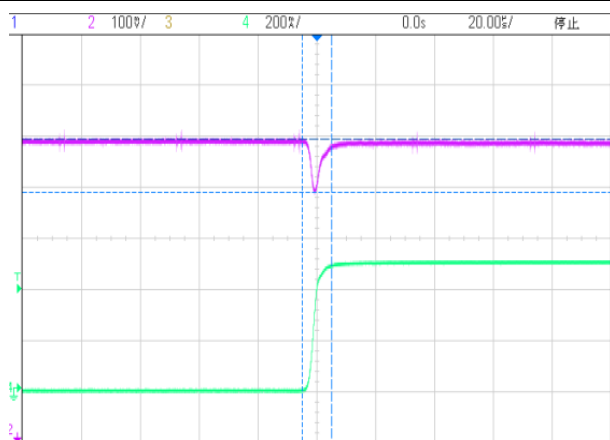
PSRR



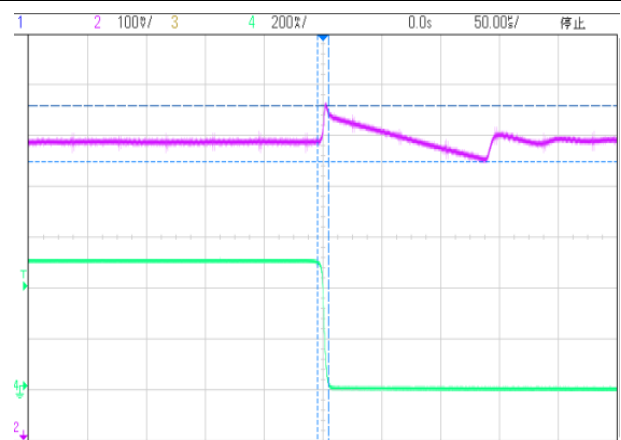
Input Transient(1.35~5.5V t=10us 1mA)



Input Transient(5.5~1.35V)



Load Transient(1mA~0.5A t=10us)

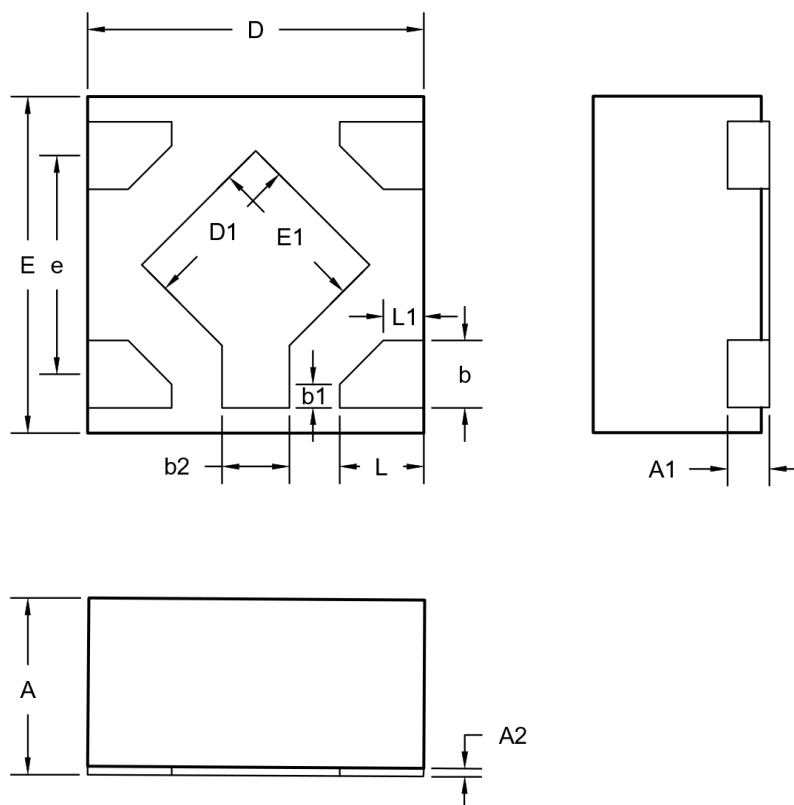


Load Transient(0.5A~1mA t=10us)

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Package Dimension

DFN4(1.2x1.2)

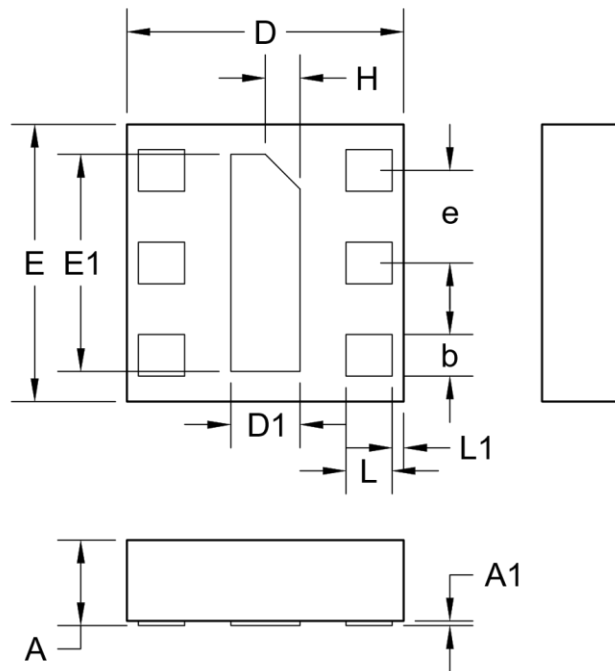


COMMON DIMENSIONS
(UNITS OF MEASURE=MILLIMETER)

SYMBOL	MIN	NOM	MAX
A	0.35	0.40	0.45
A1	0.13REF		
A2	0.00	0.02	0.05
b	0.25	0.30	0.35
b1	0.12REF		
b2	0.15	0.20	0.25
D	1.15	1.20	1.25
D1	0.58	0.63	0.68
E	1.15	1.20	1.25
E1	0.58	0.63	0.68
e	0.8BSC		
L	0.25	0.30	0.35
L1	0.12REF		

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DFN6(1.2x1.2)

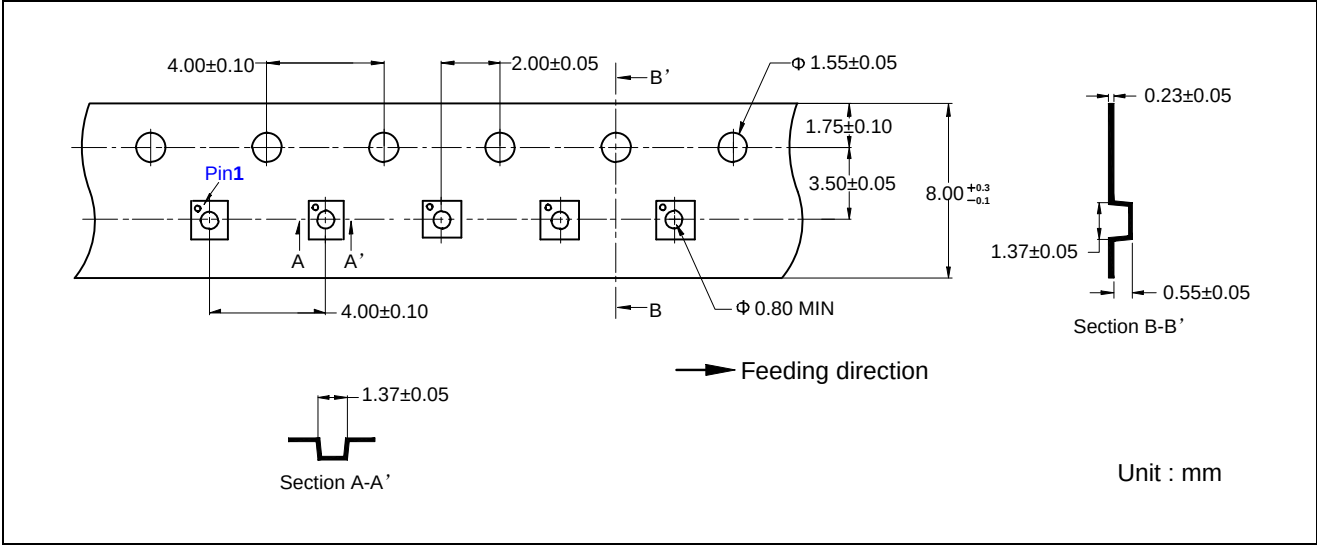


COMMON DIMENSIONS
(UNITS OF MEASURE=MILLIMETER)

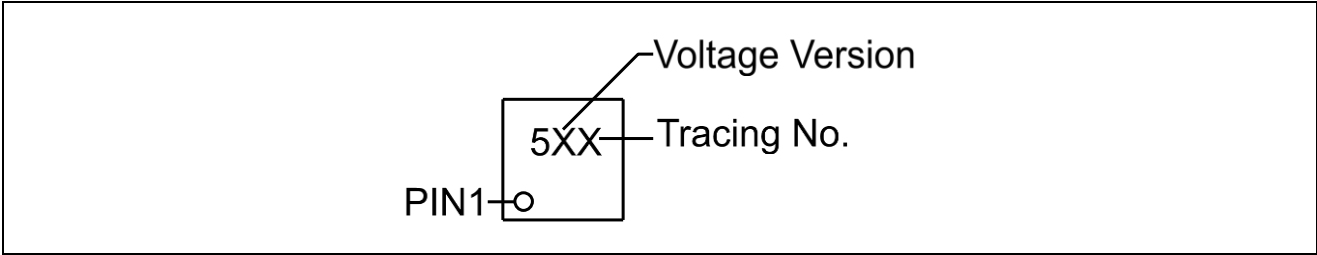
SYMBOL	MIN	NOM	MAX
A	0.34	0.37	0.50
A1	0	0.02	0.05
b	0.13	0.18	0.23
D	1.10	1.20	1.30
D1	0.25	0.30	0.35
E	1.10	1.20	1.30
E1	0.89	0.94	0.99
e	0.30	0.40	0.50
L	0.15	0.20	0.25
L1	0	0.05	0.10
H	0.15REF		

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Reel



Marking Information



<u>X</u> Voltage Version		<u>X</u>
A	1.2V	Tracing Number
I	1.1V	
U	1.05V	
5	ADJ	

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Revision History and Checking Table

Version	Date	Revision Item	Modifier	Function & Spec Checking	Package & Tape Checking
1.0	2018-10-15	Preliminary Version	Liu Zhen Chao	Zhu Jun Li	Zhu Jun Li
1.1	2019-02-27	Add TTSD&TTSR in EC table , revise test condition of ILIM, revise the functional description	Liuyg	Liujy	Liujy
1.2	2019-04-04	Up to 800mA	Liuyg	Liujy	Liujy
1.3	2022-09-03	Update Typeset	Tu Guo Zhu	Liuyg	Liujy
1.4	2023-7-19	BIAS current add note ,thickness	Shi bo	Liuyg	Liujy
1.5	2025-10-15	Update Device information	Shi bo	Liuyg	Liujy